TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

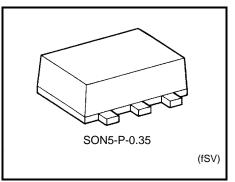
TC7SH14FS

SCHMITT INVERTER

Features

High speed: $t_{pd} = 5.5$ ns (typ.) at $V_{CC} = 5$ V Low power dissipation: $I_{CC} = 2 \ \mu A$ (max) at Ta = 25°C High noise immunity: $V_{NIH} = V_{NIL} = 28\% \ V_{CC}$ (min) 5.5V tolerant input.

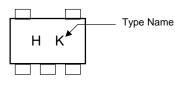
Wide operating voltage range: V_{CC} (opr) = 2~5.5 V

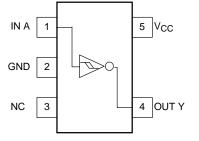




Pin Assignment

Weight : 0.001 g (Typ.)





Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	50	mW
Storage temperature	T _{stg}	-65~150	°C

Logic Diagram

Truth Table



А	Y
L	Н
Н	L

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test				Ta = 25°C		$Ta = -40 \sim 85^{\circ}C$			
		Circuit	Test Condition			Min	Тур.	Max	Min	Max	Unit
Positive					3.0	_	_	2.20	_	2.20	
Threshold	VP		_		4.5	_		3.15		3.15	V
voltage					5.5	_		3.85		3.85	
Negative					3.0	0.90	—	_	0.90	—	
Threshold	VN	—	—		4.5	1.35	—		1.35	—	V
voltage					5.5	1.65			1.65		
TT / -					3.0	0.30	—	1.20	0.30	1.20	
Hysteresis voltage	VH		_		4.5	0.40	—	1.40	0.30	1.40	V
voltage					5.5	0.30	—	1.60	0.30	1.60	
				I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	V
					3.0	2.9	3.0	_	2.9	_	
High-level output voltage	VOH		V _{IN} = V _{IL}		4.5	4.4	4.5	_	4.4	_	
				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	
				$I_{OH} = -8 \text{ mA}$	4.5	3.94		_	3.80	_	
			V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	_	0.0	0.1	_	0.1	- - - V
					3.0	_	0.0	0.1	_	0.1	
Low-level output V _{OL}	V _{OL}				4.5	_	0.0	0.1	_	0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_		0.36		0.44	
				I _{OL} = 8 mA	4.5	—		0.36		0.44	
Input leakage current	I _{IN}	_	V _{IN} = 5.5 V or GND		0~ 5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc		$V_{IN} = V_{CC}$ or GND		5.5	_		2.0	_	20.0	μA

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics Symbol	Symbol	Test	٦	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
	Circuit		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit	
$\begin{array}{llllllllllllllllllllllllllllllllllll$				3.3 ± 0.3	15	_	8.3	12.8	1.0	15.0	ns
	·	_			50	_	10.8	16.3	1.0	18.5	
				5.0 ± 0.5	15	_	5.5	8.6	1.0	10.0	
			5.0 ± 0.5	50	_	7.0	10.6	1.0	12.0		
Input capacitance	C _{IN}	_		_		_	4	10		10	pF
Power dissipation capacitance	C _{PD}	_			(Note)		14	_			pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

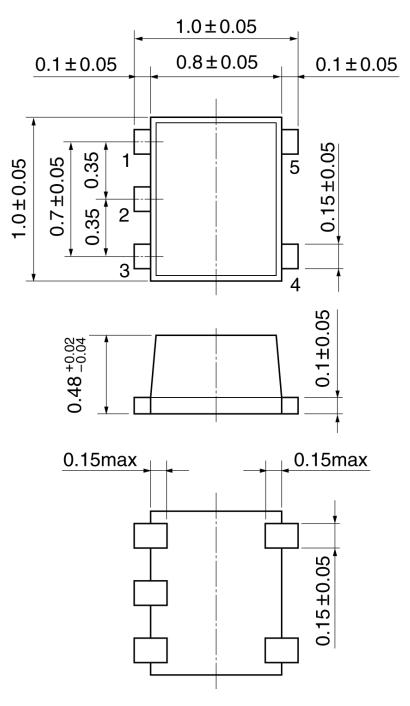
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TOSHIBA

Package Dimensions

SON5-P-0.35

Unit:mm



Weight: 0.001 g (typ.)

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